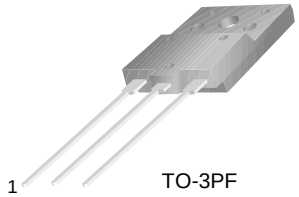
FAIRCHILD
SEMICONDUCTOR®

TIP140F/141F/142F

Monolithic Construction With Built In Base-Emitter Shunt Resistors

- Complement to TIP145F/146F/147F
- High DC Current Gain : h_{FE} = 1000 @ V_{CE} = 4V, I_C = 5A (Min.)
- Industrial Use



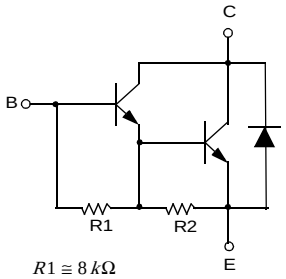
TO-3PF
1.Base 2.Collector 3.Emitter

NPN Epitaxial Darlington Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter		Value	Units
V_{CBO}	Collector-Base Voltage	: TIP140F	60	V
		: TIP141F	80	V
		: TIP142F	100	V
V_{CEO}	Collector-Emitter Voltage	: TIP140F	60	V
		: TIP141F	80	V
		: TIP142F	100	V
V_{EBO}	Emitter-Base Voltage		5	V
I_C	Collector Current (DC)		10	A
I_{CP}	Collector Current (Pulse)		15	A
I_B	Base Current (DC)		0.5	A
P_C	Collector Dissipation (T_C=25°C)		60	W
T_J	Junction Temperature		150	°C
T_{STG}	Storage Temperature		- 65 ~ 150	°C

Equivalent Circuit



$R1 \cong 8\,k\Omega$
$R2 \cong 0.12\,k\Omega$

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V_{CEO}(sus)	Collector-Emitter Sustaining Voltage					
	: TIP140F	I_C = 30mA, I_B = 0	60			V
	: TIP141F		80			V
	: TIP142F		100			V
I_{CEO}	Collector Cut-off Current					
	: TIP140F	V_{CE} = 30V, I_B = 0			2	mA
	: TIP141F	V_{CE} = 40V, I_B = 0			2	mA
	: TIP142F	V_{CE} = 50V, I_B = 0			2	mA
I_{CBO}	Collector Cut-off Current					
	: TIP140F	V_{CB} = 60V, I_E = 0			1	mA
	: TIP141F	V_{CB} = 80V, I_E = 0			1	mA
	: TIP142F	V_{CB} = 100V, I_E = 0			1	mA
I_{EBO}	Emitter Cut-off Current	V_{BE} = 5V, I_C = 0			2	mA
h_{FE}	DC Current Gain	V_{CE} = 4V, I_C = 5A	1000			
		V_{CE} = 4V, I_C = 10A	500			
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 5A, I_B = 10mA			2	V
		I_C = 10A, I_B = 40mA			3	V
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C = 10A, I_B = 40mA			3.5	V
V_{BE}(on)	Base-Emitter On Voltage	V_{CE} = 4V, I_C = 10A			3	V
t_D	Delay Time	V_{CC} = 30V, I_C = 5A		0.15		µs
t_R	Rise Time	$I_{B\,1}$= 20mA, I_{B2} = -20mA		0.55		µs
t_{STG}	Storage Time	R_L = 6Ω		2.5		µs
t_F	Fall Time			2.5		µs

Typical Characteristics

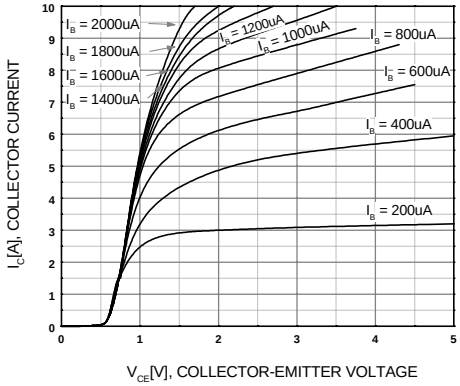


Figure 1. Static Characteristics

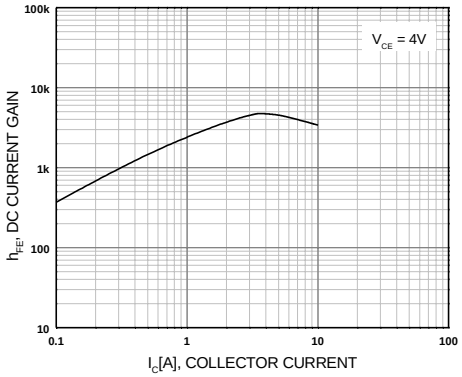


Figure 2. DC current Gain

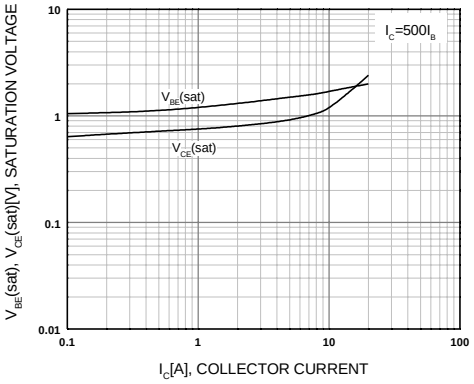


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

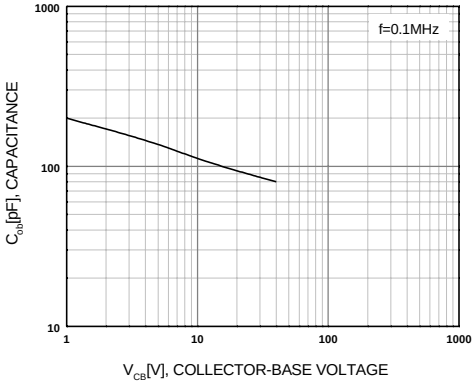


Figure 4. Collector Output Capacitance

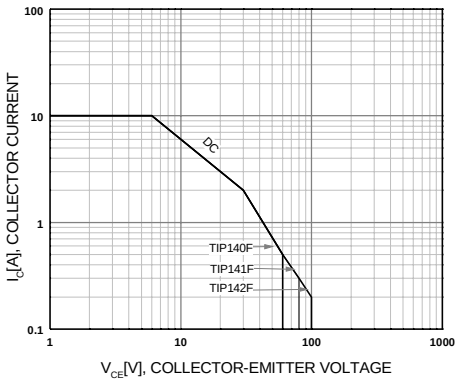


Figure 5. Safe Operating Area

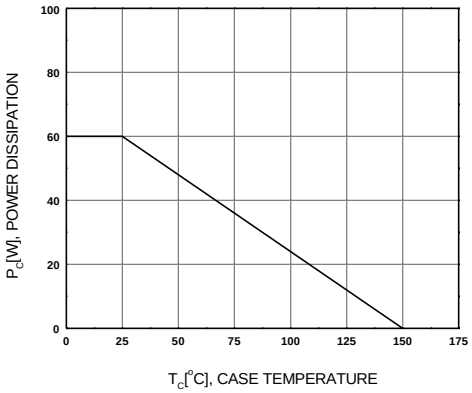
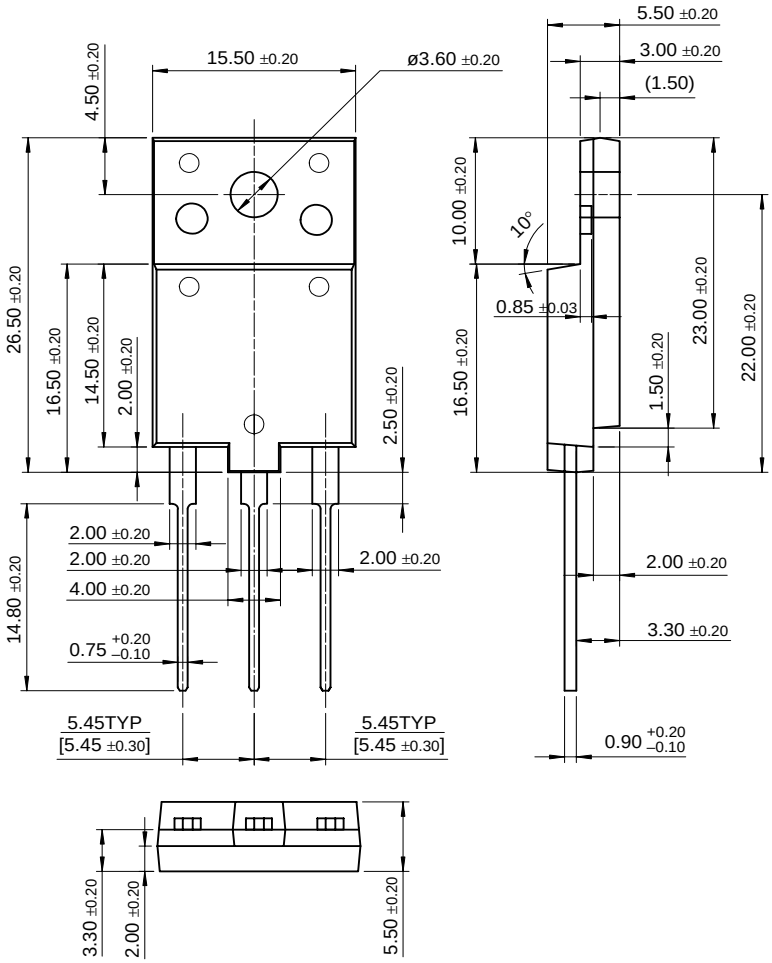


Figure 6. Power Derating

Package Dimensions

TO-3PF



Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	FACT™	ImpliedDisconnect™	PACMAN™	SPM™
ActiveArray™	FACT Quiet series™	ISOPLANAR™	POP™	Stealth™
Bottomless™	FAST®	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E^2CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C™	OCX™	RapidConfigure™	UHC™
Across the board. Around the world.™		OCXPro™	RapidConnect™	UltraFET®
The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR INTERNATIONAL.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.